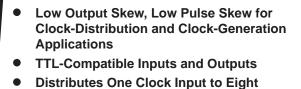
CDC340 1-LINE TO 8-LINE CLOCK DRIVER

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- Outputs
 Distributed V_{CC} and Ground Pins Reduce
- High-Drive Outputs (-48-mA I_{OH}, 48-mA I_{OL})

Switching Noise

- State-of-the-Art EPIC-IIB™ BiCMOS Design Significantly Reduces Power Dissipation
- Package Options Include Plastic Small-Outline (DW) and Shrink

DW PACKAGE (TOP VIEW) 20 VCC V_{CC} 1G [19 1Y1 2G 🛮 3 18 1Y2 ΑП 17 | GND P0 **∏** 5 16 1Y3 P1 [] 6 15 1Y4 14 GND Vcc [2Y4 **1** 8 13 7 2Y1 2Y3 **[** 9 12 2Y2 11 GND GND **1** 10

description

The CDC340 is a high-performance clock-driver circuit that distributes one (A) input signal to eight (Y) outputs with minimum skew for clock distribution. Through the use of the control pins (1G and 2G), the outputs can be placed in a high state regardless of the A input.

The propagation delays are adjusted at the factory using the P0 and P1 pins. These pins are not intended for customer use and should be strapped to GND.

The CDC340 is characterized for operation from 0°C to 70°C.

FUNCTION TABLE

	INPUTS		OUTPUTS				
1G	2G	Α	1Y1-1Y4	2Y1-2Y4			
Х	Χ	L	Н	Н			
L	L	Н	Н	Н			
L	Н	Н	Н	L			
Н	L	Н	L	Н			
Н	Н	Н	L	L			

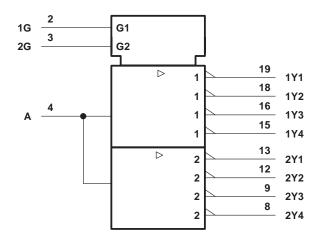


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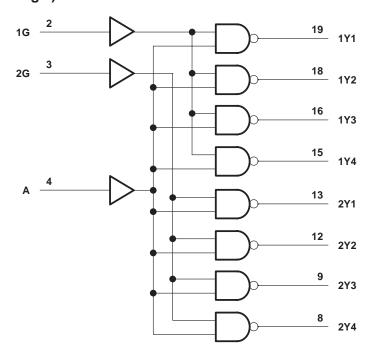


logic symbol†



[†] This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)





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absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage range, V _{CC}	0.5 V to 7 V
Input voltage range, V _I (see Note 1)	
Voltage range applied to any output in the high state or power-off state,	
V _O (see Note 1)	$-0.5 \text{ V to V}_{CC} + 0.5 \text{ V}$
Current into any output in the low state, I _O	96 mA
Input clamp current, $I_{ K }(V_1 < 0)$	–18 mA
Maximum power dissipation at $T_A = 55^{\circ}C$ (in still air) (see Note 2): DW package	1.6 W
Storage temperature range, Teta	65°C to 150°C

[†] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- NOTES: 1. The input and output negative-voltage ratings may be exceeded if the input and output clamp-current ratings are observed.
 - The maximum package power dissipation is calculated using a junction temperature of 150°C and a board trace length of 750 mils.
 For more information, refer to the *Package Thermal Considerations* Application Note in the *ABT Advanced BiCMOS Technology Data Book*, literature number SCBD002.

recommended operating conditions (see Note 3)

			MIN	MAX	UNIT
Vсс	Supply voltage		4.75	5.25	V
VIH	High-level input voltage		2		V
VIL	Low-level input voltage			0.8	V
VI	Input voltage		0	Vcc	V
ЮН	High-level output current			-48	mA
lOL	Low-level output current			48	mA
f _{clock}		One output back loaded		80	MHz
	Input clock frequency	Both output banks loaded		40	IVITZ
TA	Operating free-air temperature		0	70	°C

NOTE 3: Unused inputs must be held high or low to prevent them from floating.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS			T _A = 25°C			MIN	MAX	UNIT
PARAMETER	1	EST CONDITIONS		MIN	TYP‡	T MAX		WAX	UNII
VIK	$V_{CC} = 4.75 \text{ V},$	$I_{I} = -18 \text{ mA}$				-1.2		-1.2	V
	$V_{CC} = 4.75 \text{ V},$	$I_{OH} = -3 \text{ mA}$		2.5			2.5		
Voн	V _{CC} = 5 V,	$I_{OH} = -3 \text{ mA}$		3			3		V
	V _{CC} = 4.75 V,	$I_{OH} = -48 \text{ mA}$		2			2		
V _{OL}	$V_{CC} = 4.75 \text{ V},$	$I_{OL} = 48 \text{ mA}$						0.5	V
lį	$V_{CC} = 5.25 \text{ V},$	$V_I = V_{CC}$ or GND				±1		±1	μΑ
IO§	$V_{CC} = 5.25 \text{ V},$	$V_0 = 2.5 \text{ V}$		-50	-100	-200	-50	-200	mA
loo	V _{CC} = 5.25 V,	I _O = 0,	Outputs high		2			3.5	mA
Icc	$V_I = V_{CC}$ or GND		Outputs low		24			33	IIIA
Ci	V _I = 2.5 V or 0.5 V				3	·			pF

 $[\]ddagger$ All typical values are at $V_{CC} = 5 \text{ V}$.



[§] No more than one output should be tested at a time, and the duration of the test should not exceed one second.

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switching characteristics, $C_L = 50 pF$ (see Figure 1 and Figure 2)

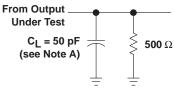
PARAMETER		FROM (INPUT)	TO (OUTPUT)	V _{CC} = 5 V, T _A = 25°C			V _{CC} = 4.75 V to 5.25 V, T _A = 0°C to 70°C		UNIT
				MIN	TYP	MAX	MIN	MAX	
tPLH	Propagation delay time, low-to-high level	Α		3.4		4.5	3	4.8	no
tPHL	Propagation delay time, high-to-low level	A	ī	3.2		4.3	2.8	4.7	ns
tPLH	Propagation delay time, low-to-high level	G	V	2		3.8	2	4	ns
tPHL	Propagation delay time, high-to-low level		Ī	2		3.8	2	4	115
t _{sk(o)}	Skew time, output				0.3	0.5		0.6	
tsk(p)	Skew time, pulse	А	Υ		0.6	0.8		0.9	ns
tsk(pr)	Skew time, process					1.1		1.1	
t _r	Rise time	А	Υ					1.5	ns
t _f	Fall time	А	Υ					1.5	ns

$t_{\mbox{\scriptsize pd}}$ performance information relative to $V_{\mbox{\scriptsize CC}}$ and temperature variation (see Note 4)

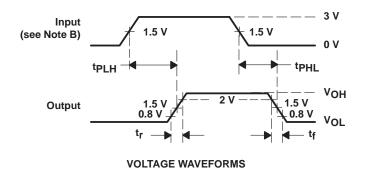
	PARAMETER	∆ change
∆t _{PLH(TA)} †	Temperature drift of tpLH from 0°C to 70°C	−53 ps/10°C
Δt _{PHL(TA)} †	Temperature drift of tpHL from 0°C to 70°C	−58 ps/10°C
∆tPLH(VCC) [‡]	V _{CC} drift of t _{PLH} from 4.75 V to 5.25 V	43 ps/100 mV
∆tPHL(VCC) [‡]	V _{CC} drift of t _{PHL} from 4.75 V to 5.25 V	-33 ps/100 mV

† Virtually independent of V_{CC}
‡ Virtually independent of temperature
NOTE 4: The data extracted is from a wide range of characterization material.

PARAMETER MEASUREMENT INFORMATION



LOAD CIRCUIT

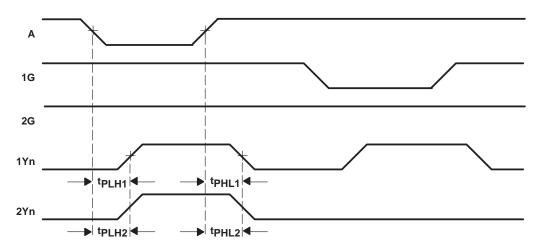


NOTES: A. C_L includes probe and jig capacitance.

B. All input pulses are supplied by generators having the following characteristics: PRR \leq 10 MHz, Z_{O} = 50 Ω , $t_{\Gamma} \leq$ 2.5 ns, $t_{\Gamma} \leq$ 2.5 ns.

Figure 1. Load Circuit and Voltage Waveforms

PROPAGATION DELAY TIMES



NOTES: A. Output skew, $t_{Sk(O)}$, is calculated as the greater of:

- The difference between the fastest and slowest of tpLHn (n = 1, 2)
- The difference between the fastest and slowest of t_{PHLn} (n = 1, 2)
- B. Pulse skew, $t_{sk(p)}$, is calculated as the greater of | $t_{PLHn} t_{PHLn}$ | (n = 1, 2).
- C. Process skew, $t_{sk(pr)}$, is calculated as the greater of:
 - The difference between the fastest and slowest of tpLHn (n = 1, 2) across multiple devices under identical operating conditions
 - $\ \, \text{The difference between the fastest and slowest of tp}_{HLn} \, (n=1,2) \, \text{across multiple devices under identical operating conditions} \, \, \text{the difference between the fastest and slowest of tp}_{HLn} \, (n=1,2) \, \text{across multiple devices under identical operating conditions} \, \text{the difference between the fastest and slowest of tp}_{HLn} \, (n=1,2) \, \text{across multiple devices under identical operating conditions} \, \text{the difference between the fastest and slowest of tp}_{HLn} \, (n=1,2) \, \text{across multiple devices under identical operating conditions} \, \text{the difference between the fastest and slowest of tp}_{HLn} \, (n=1,2) \, \text{across multiple devices under identical operating conditions} \, \text{the difference between the difference between$

Figure 2. Waveforms for Calculation of $t_{sk(p)}$, $t_{sk(p)}$, $t_{sk(pr)}$



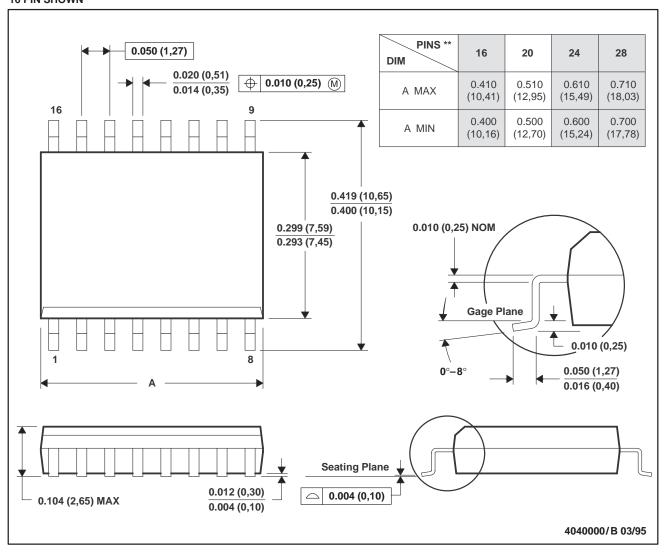
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MECHANICAL INFORMATION

DW (R-PDSO-G**)

PLASTIC SMALL-OUTLINE PACKAGE

16 PIN SHOWN



NOTES: A. All linear dimensions are in inches (millimeters).

- B. This drawing is subject to change without notice.
- C. Body dimensions do not include mold flash or protrusion not to exceed 0.006 (0,15).
- D. Falls within JEDEC MS-013

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